One Cell Lithium-ion/Polymer Battery Protection IC

GENERAL DESCRIPTION

T318 is a spacing saving single chip lithiumion/polymerbatteryprotection IC. Integrating power MOSFET and only two external components makes the protection board highly compact. T318 has full protection including over charging voltage protection, over discharging protection, over current protection, short protection and over temperature protection. The very low standbycurrentdrains little current from the cellwhile instorage. T318 is available in 8 PIN SOP8_ package.

FEATURES

- · Integrate low Rdson Power MOSFET
- · SOP8 Package
- · Over-temperature Protection
- · Two-steps Over current protection
- · High-accuracy Voltage Detection
- · Low Current Consumption
 - Operation Mode: 2.5µA typ.
 - Power-down Mode: 0.1µA typ.
 RoHS Compliant and Lead (Pb) Free

APPLICATIONS

One-Cell Lithium-ion Battery Pack Lithium-Polymer Battery Pack

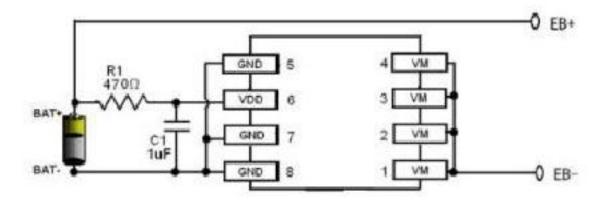


Figure 1. Typical Application Circuit

DESCRIPTION

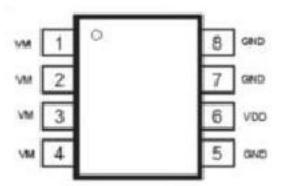


Figure 2. PIN Configuration

Number	Name	Description
1,2,3,4	VM	The negative terminal of the battery pack. The internal FET switch connects this terminal to GND
5,7,8	GND	Ground, connect the negative terminal of the battery to this pin
6	VDD	Power Supply

ORDERING INFORMATION

PART NUMBE R	Pa ck ag e	Overcharg e Detection Voltage [VCU] (V)	Overchar ge Release Voltage [VCL] (V)	Overdischar ge Detection Voltage [VDL] (V)	Overdischar ge Release Voltage [VDR] (V)	Overcurr ent Detection Current [IOV1] (A)	Top Mark
T318	S O P8	4.28	4.10	2.40	3.0	4.0	T318s

Function Block Diagram

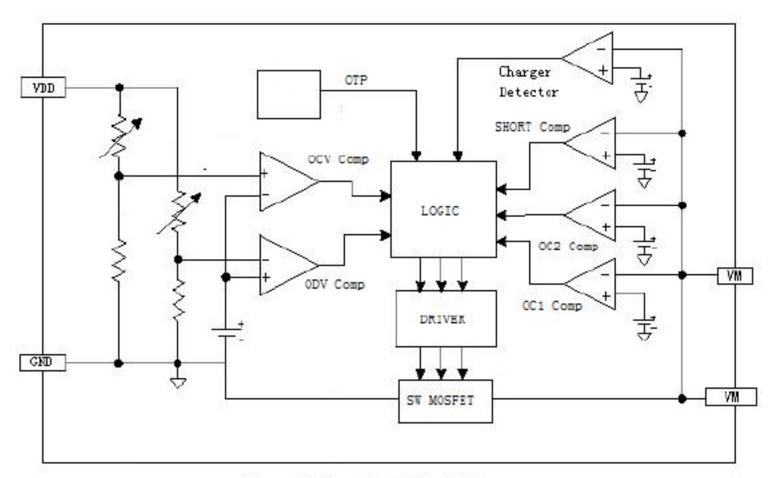


Figure 3. Functional Block Diagram

ABSOLUTE MAXIMUM RATINGS

(Note: Do not exceed these limits to prevent damage to the device. Exposure to absolute maximum rating conditions for long periods may affect device reliability.)

PARAMETER	VALUE	UNIT
VDD input pin voltage	-0.3 to6	V
VM input pin voltage	-6 to 10	V
Operating Ambient Temperature	-40 to 85	°C
Maximum Junction Temperature	125	°C
Storage Temperature	-55 to 150	°C
Lead Temperature (Soldering, 10 sec)	300	°C
Power Dissipation at T=25°C	0.4	w
Package Thermal Resistance (Junction to Ambient) θJA	250	°C/W
Package Thermal Resistance (Junction to Case) θJC	130	°C/W
ESD	2000	v

ABSOLUTE MAXIMUM RATINGS

 $TypicallyT_A = 27^{\circ}C$, VDD=3.7V unless otherwisespecified

Parameter	Symbol	TestCondit ion	Mi n	Ту Р	M ax	Unit
Detection Voltage						
OverchargeProtectionVoltage	V _{ocv}		4.275	4.30	4.375	٧
Overcharge Protection ReleaseVoltage	V _{OCR}		4.10	4.15	4.22	٧
Overdischarge ProtectionVoltage	V _{odv}		2.3	2.4	2.5	٧
Overdischarge Protection Release Voltage	V _{ODR}		2.9	3.0	3.1	٧
ChargerDetection Voltage	V _{CHA}		-0.07	-0.12	-0.2	٧
DetectionCurrent	100		100		3	
Class1 Overdischarge ProtectionCurrent	l _{oci1}			5		А

Class2 Overdischarge Protection Current	I _{OC12}			14		А
Load Short- CircuitingDetection	SHORT			21		А
Overcharge ProtectionCurrent	I _{CHA}		4	7	10	А
CurrentConsumption						
CurrentConsumptioninNor malOperation	I _{OPE}	V _{D`D} =3.9VVM =0V		2.5		μА
CurrentConsumptioninpowerD own	I PDN	V _{DD} =2.0V VM pinfloating		0.1		μА
VMInternal Resistance	'	·				
InternalResistanceb etweenVMandV _{DD}	R _{VMD}	V _D =3.5VVM=1 .0V		320		kΩ
InternalResistancebetweenV MandGND	R _{VMS}	V _{DD} =2.0VV M=1.0V		100		kΩ
FETonResistance						1.
EquivalentFETonResistance	R _{DS(ON)}	V _{DD} =3.6VI _V _M =1.0A		25		mΩ
Over Temperature Protection						
Over Temperature Protection	T _{SHD+}			120		°c
Over Temperature Recovery Degree	T _{SHD} .			100		°c
Detection Delay Time	,	7)	20:	**		300
Overcharge Voltage Detection Delay Time	t _{ocv}			130		mS
Overdischarge Voltage Detection Delay Time	t			40		m S
Overdischarge Current1Delay Time	t _{IOV 1}			10		mS
Overdischarge Current2Delay Time	t _{IOV2}	7		5		mS
Load Short- Circuiting Detection Delay Time	t SHORT	Vdd=3.5V		75		uS

Description of Operation

Overcharge Protection

When the voltage of the battery cell exceeds the overcharge protection voltage (Vocv)

beyond the overcharge delay time (tocv)
period, charging is inhibited by turning off
power MOSFET. The overcharge condition is
released in two cases:

- The voltage of the battery cell becomes lower than the overcharge release voltage (OCR) through self-discharge.
- 2. The voltage of the battery cell falls below the overcharge protection voltage (Vocv) and a load is connected. When the battery voltage is above Vocv, the overcharge condition will not release even a load is connected to the pack.

Overdischarge Protection

When the voltage of the battery cell goes below the overdischarge protection voltage (VoDV) beyond the overdischarge delay time (toDV) period, discharging is inhibited. Inhibition of discharging is immediately released when the voltage of the battery cell becomes higher than overdischarge release voltage (VoDR).

Overcurrent Protection

When the discharging current becomes higher than a specified Overdischarge Current and beyond over discharge current delay time period, discharging is inhibited. Inhibition of discharging is immediately released when the load is released or the impedance between EB+ and EB- is larger than 500kΩ. The T318 provides three over current detection levels (8A, 14A and 36A) with three over current delay time (tov1, tov2andtshort) corresponding to each over current detection level.

Over Temperature Protection

When IC temperature becomes higher than a specified value, T318 will turn off Power MOSFET whatever in discharging or charging condition. In discharging condition, Inhibition of discharging is released when temperature lower than Over Temperature Recovery Degree (100 °C) and load also released. In charging condition, Inhibition of charging is released when temperature lower than over temperature

recovery degree(100 °C) and charger also removed.

Over Charging Current Protection
When the charging current becomes higher
than discharge protection Current (CHA)
andbeyond over discharge current delay time
period, charging is inhibited. Inhibition of
charging is immediately released when the
charger is removed.

Charger detection after Overdischarge
When over discharge occurs, discharging is
inhibited. However, charging is still permitted
through the parasitic diode of MOSFET. Once
the charger is connected to the battery pack,
T318 detects the voltage between VM and
GND is below charge detection threshold
voltage (CHA), Power MOSFET will turn on
when Battery cell voltage is higher than
Overdischarge Protection Voltage.

Power Saving after Overdischarge When overdischarge occurs, the T318 will enter into power-down mode.

Timing Diagram

3. Over Discharge Current (ODC)State →Normal State

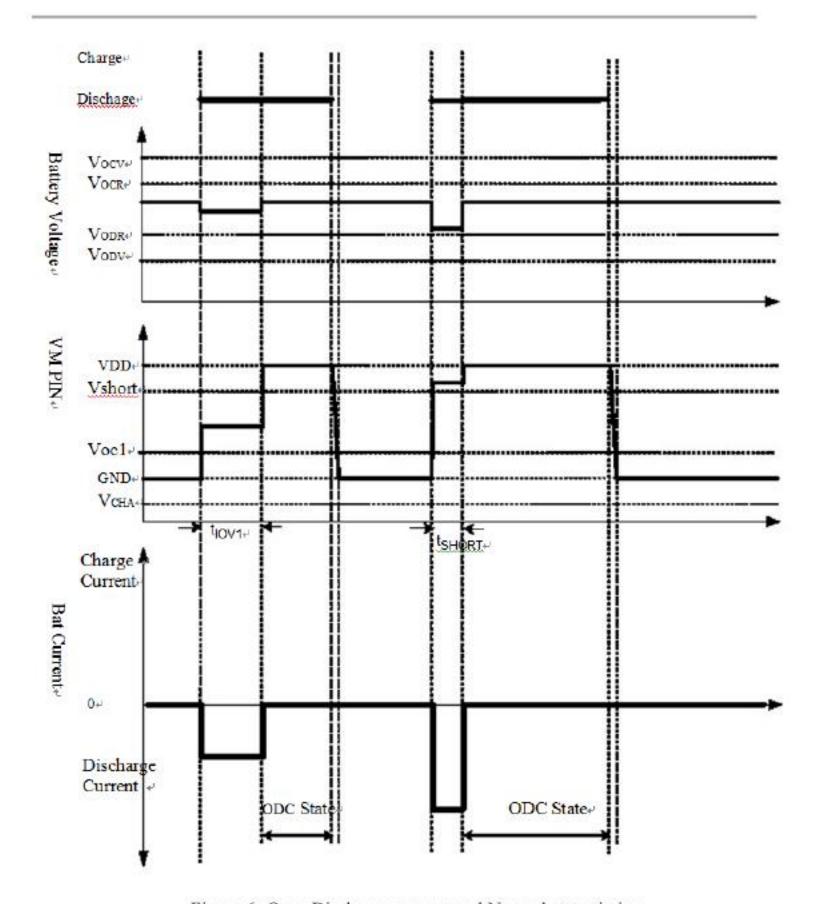


Figure 6. Over Discharge current and Normal state timing

TYPICAL APPLICATION

As shown in Figure 7, the bold line is the high density current path which must be kept as short as possible. For thermal management, ensure that these trace widths are adequate. C1 is a decoupling capacitor which should be placed as close as possible to T318.

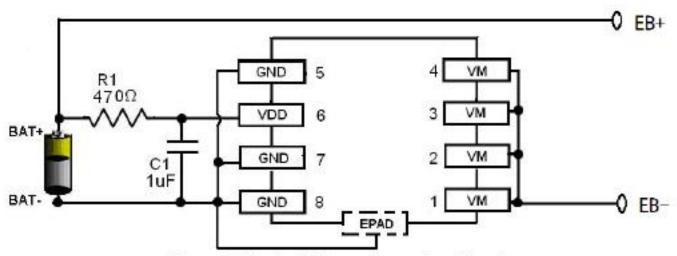


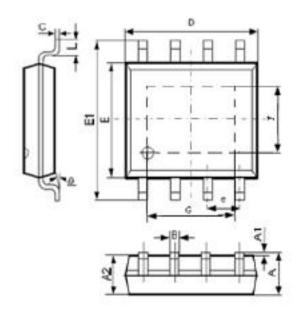
Figure 7. Typical Battery Protection Circuit

Precautions

- Pay attention to the operating conditions for input/output voltage and load current so that the power loss in T318 does not exceed the power dissipation of the package.
- Do not apply an electrostatic discharge to this T318 that exceeds the performance ratings of the built-in electrostatic protection circuit.

PACKAGE OUTLINE

SOP8_ PACKAGE OUTLINE AND DIMENSIONS



SYMBOL	2000	sion in neters	Dimension in Inches		
	MIN	MAX	MIN	MAX	
A	1.35	1.75	0.053	0.069	
A1.	0.100	0.250	0.004	0.010	
A2	1.350	1.550	0.053	0.061	
В	0.330	0.510	0.013	0.020	
С	0.190	0.250	0.007	0.010	
D	4.700	5.100	0.185	0.201	
E	3.800	4.000	0.150	0.157	
E1	5.800	6.300	0.228	0.248	
е	1.27	TYP	0.050 TYP		
L	0.400	1.270	0.016	0.050	
θ	0°	8°	0°	80	
F	2.26	2.56	0.089	0.101	
Ġ	3.15	3.45	0.124	0.136	

